Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Analog Devices Inc.
ADA4861-3YRZ-RL

For any questions, you can email us directly:
sales@integrated-circuit.com

Distributor of Analog Devices Inc.: Excellent Integrated System Limited
Datasheet of ADA4861-3YRZ-RL - IC OPAMP CFA 370MHZ 14SOIC
Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

High Speed, Low Cost, Triple Op Amp

ADA4861-3

FEATURES

High speed
- **730 MHz, −3 dB bandwidth**
- **625 V/µs slew rate**
- **13 ns settling time to 0.5%**

Wide supply range: 5 V to 12 V
Low power: 6 mA/amplifier
0.1 dB flatness: 100 MHz
Differential gain: 0.01%
Differential phase: 0.02°
Low voltage offset: 100 µV (typical)
High output current: 25 mA
Power down

PIN CONFIGURATION

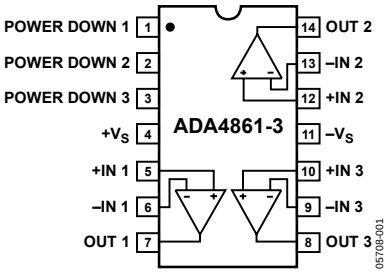


Figure 1.

APPLICATIONS

Consumer video
Professional video
Broadband video
ADC buffers
Active filters

GENERAL DESCRIPTION

The ADA4861-3 is a low cost, high speed, current feedback, triple op amp that provides excellent overall performance. The 730 MHz, −3 dB bandwidth, and 625 V/µs slew rate make this amplifier well suited for many high speed applications. With its combination of low price, excellent differential gain (0.01%), differential phase (0.02°), and 0.1 dB flatness out to 100 MHz, this amplifier is ideal for both consumer and professional video applications.

The ADA4861-3 is designed to operate on supply voltages as low as +5 V and up to ±5 V using only 6 mA/amplifier of supply current. To further reduce power consumption, each amplifier is equipped with a power-down feature that lowers the supply current to 0.3 mA/amplifier when not being used.

The ADA4861-3 is available in a 14-lead SOIC_N package and is designed to work over the extended temperature range of −40°C to +105°C.

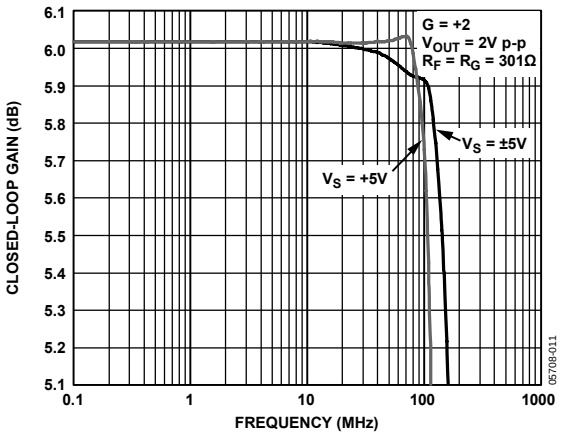


Figure 2. Large Signal 0.1 dB Flatness

Rev. A
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700 **www.analog.com**
Fax: 781.461.3113
©2006 Analog Devices, Inc. All rights reserved.

TABLE OF CONTENTS

Features ... 1
Applications ... 1
Pin Configuration ... 1
General Description ... 1
Revision History ... 2
Specifications ... 3
Absolute Maximum Ratings ... 5
Thermal Resistance ... 5
ESD Caution ... 5
Typical Performance Characteristics ... 6
Applications ... 13
Gain Configurations ... 13
20 MHz Active Low-Pass Filter ... 13
RGB Video Driver ... 14
Driving Two Video Loads ... 14
POWER-DOWN Pins ... 14
Single-Supply Operation ... 15
Power Supply Bypassing ... 15
Layout ... 15
Outline Dimensions ... 16
Ordering Guide ... 16

REVISION HISTORY

3/06—Rev 0 to Rev. A
Changes to 20 MHz Active Low-Pass Filter Section ... 13
Changes to Figure 48 and Figure 49 ... 13

10/05—Revision 0: Initial Version

SPECIFICATIONS

V_S = +5 V (@ T_A = 25°C, G = +2, R_L = 150 Ω, C_L = 4 pF, unless otherwise noted); for G = +2, R_F = R_G = 301 Ω; and for G = +1, R_F = 499 Ω.

Table 1.

Parameter	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
−3 dB Bandwidth	V_O = 0.2 V p-p		350		MHz
	V_O = 2 V p-p		145		MHz
	G = +1, V_O = 0.2 V p-p		560		MHz
Bandwidth for 0.1 dB Flatness	V_O = 2 V p-p		85		MHz
+Slew Rate (Rising Edge)	V_O = 2 V p-p		590		V/µs
−Slew Rate (Falling Edge)	V_O = 2 V p-p		480		V/µs
Settling Time to 0.5% (Rise/Fall)	V_O = 2 V step		12/13		ns
NOISE/DISTORTION PERFORMANCE					
Harmonic Distortion HD2/HD3	f_C = 1 MHz, V_O = 2 V p-p		−81/−89		dBc
Harmonic Distortion HD2/HD3	f_C = 5 MHz, V_O = 2 V p-p		−69/−76		dBc
Input Voltage Noise	f = 100 kHz		3.8		nV/√Hz
Input Current Noise	f = 100 kHz, +IN/−IN		1.7/5.5		pA/√Hz
Differential Gain			0.02		%
Differential Phase			0.03		Degrees
All-Hostile Crosstalk	Amplifier 1 and Amplifier 2 driven, Amplifier 3 output measured, f = 1 MHz		−65		dB
DC PERFORMANCE					
Input Offset Voltage		−13	−0.9	+13	mV
+Input Bias Current		−2	−0.8	+1	µA
−Input Bias Current		−8	+2.3	+13	µA
Open-Loop Transresistance		400	620		kΩ
INPUT CHARACTERISTICS					
Input Resistance	+IN		14		MΩ
	−IN		85		Ω
Input Capacitance	+IN		1.5		pF
Input Common-Mode Voltage Range	G = +1		1.2 to 3.8		V
Common-Mode Rejection Ratio	V_{CM} = 2 V to 3 V	−54	−56.5		dB
POWER-DOWN PINS					
Input Voltage	Enabled		0.6		V
	Power down		1.8		V
Bias Current	Enabled		−3		µA
	Power down		115		µA
Turn-On Time			200		ns
Turn-Off Time			3.5		µs
OUTPUT CHARACTERISTICS					
Output Overdrive Recovery Time (Rise/Fall)	V_{IN} = +2.25 V to −0.25 V		55/100		ns
Output Voltage Swing	R_L = 150 Ω	1.2 to 3.8	1.1 to 3.9		V
	R_L = 1 kΩ	0.9 to 4.1	0.85 to 4.15		V
Short-Circuit Current	Sinking and sourcing		65		mA
POWER SUPPLY					
Operating Range		5		12	V
Total Quiescent Current	Enabled	12.5	16.1	18.5	mA
Quiescent Current/Amplifier	POWER DOWN pins = +V_S		0.2	0.33	mA
Power Supply Rejection Ratio					
+PSR	+V_S = 4 V to 6 V, −V_S = 0 V	−60	−64		dB

V_S = ±5 V (@ T_A = 25°C, G = +2, R_L = 150 Ω, C_L = 4 pF, unless otherwise noted); for G = +2, R_F = R_G = 301 Ω; and for G = +1, R_F = 499 Ω.

Table 2.

Parameter	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
−3 dB Bandwidth	V_O = 0.2 V p-p		370		MHz
	V_O = 2 V p-p		210		MHz
	G = +1, V_O = 0.2 V p-p		730		MHz
Bandwidth for 0.1 dB Flatness	V_O = 2 V p-p		100		MHz
+Slew Rate (Rising Edge)	V_O = 2 V p-p		910		V/µs
−Slew Rate (Falling Edge)	V_O = 2 V p-p		680		V/µs
Settling Time to 0.5% (Rise/Fall)	V_O = 2 V step		12/13		ns
NOISE/DISTORTION PERFORMANCE					
Harmonic Distortion HD2/HD3	f_C = 1 MHz, V_O = 2 V p-p		−85/−99		dBc
Harmonic Distortion HD2/HD3	f_C = 5 MHz, V_O = 2 V p-p		−73/−86		dBc
Input Voltage Noise	f = 100 kHz		3.8		nV/√Hz
Input Current Noise	f = 100 kHz, +IN/−IN		1.7/5.5		pA/√Hz
Differential Gain			0.01		%
Differential Phase			0.02		Degrees
All-Hostile Crosstalk	Amplifier 1 and Amplifier 2 driven, Amplifier 3 output measured, f = 1 MHz		−65		dB
DC PERFORMANCE					
Input Offset Voltage		−13	−0.1	+13	mV
+Input Bias Current		−2	−0.7	+1	µA
−Input Bias Current		−8	+2.9	+13	µA
Open-Loop Transresistance		500	720		kΩ
INPUT CHARACTERISTICS					
Input Resistance	+IN		15		MΩ
	−IN		90		Ω
Input Capacitance	+IN		1.5		pF
Input Common-Mode Voltage Range	G = +1		−3.7 to +3.7		V
Common-Mode Rejection Ratio	V_{CM} = ±2 V	−55	−58		dB
POWER-DOWN PINS					
Input Voltage	Enabled		−4.4		V
	Power down		−3.2		V
Bias Current	Enabled		−3		µA
	Power down		250		µA
Turn-On Time			200		ns
Turn-Off Time			3.5		µs
OUTPUT CHARACTERISTICS					
Output Overdrive Recovery Time (Rise/Fall)	V_{IN} = ±3.0 V		30/90		ns
Output Voltage Swing	R_L = 150 Ω	±2	−3.1 to +3.65		V
	R_L = 1 kΩ	±3.9	±4.05		V
Short-Circuit Current	Sinking and sourcing		100		mA
POWER SUPPLY					
Operating Range		5		12	V
Total Quiescent Current	Enabled	13.5	17.9	20.5	mA
Quiescent Current/Amplifier	POWER DOWN pins = +V_S		0.3	0.5	mA
Power Supply Rejection Ratio					
+PSR	+V_S = 4 V to 6 V, −V_S = −5 V	−63	−66		dB
−PSR	+V_S = 5 V, −V_S = −4 V to −6 V, POWER DOWN pins = −V_S	−59	−62		dB

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage	12.6 V
Power Dissipation	See Figure 3
Common-Mode Input Voltage	$-V_S + 1$ V to $+V_S - 1$ V
Differential Input Voltage	$\pm V_S$
Storage Temperature	−65°C to +125°C
Operating Temperature Range	−40°C to +105°C
Lead Temperature	JEDEC J-STD-20
Junction Temperature	150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, θ_{JA} is specified for device soldered in circuit board for surface-mount packages.

Table 4. Thermal Resistance

Package Type	θ_{JA}	Unit
14-lead SOIC_N	90	°C/W

Maximum Power Dissipation

The maximum safe power dissipation for the ADA4861-3 is limited by the associated rise in junction temperature (T_J) on the die. At approximately 150°C, which is the glass transition temperature, the plastic changes its properties. Even temporarily exceeding this temperature limit can change the stresses that the package exerts on the die, permanently shifting the parametric performance of the amplifiers. Exceeding a junction temperature of 150°C for an extended period can result in changes in silicon devices, potentially causing degradation or loss of functionality.

The power dissipated in the package (P_D) is the sum of the quiescent power dissipation and the power dissipated in the die due to the amplifiers' drive at the output. The quiescent power is the voltage between the supply pins (V_S) times the quiescent current (I_S).

$$P_D = Quiescent\ Power + (Total\ Drive\ Power - Load\ Power)$$

$$P_D = (V_S \times I_S) + \left(\frac{V_S}{2} \times \frac{V_{OUT}}{R_L}\right) - \frac{V_{OUT}^2}{R_L}$$

RMS output voltages should be considered.

Airflow increases heat dissipation, effectively reducing θ_{JA}. In addition, more metal directly in contact with the package leads and through holes under the device reduces θ_{JA}.

Figure 3 shows the maximum safe power dissipation in the package vs. the ambient temperature for the 14-lead SOIC_N (90°C/W) on a JEDEC standard 4-layer board. θ_{JA} values are approximations.

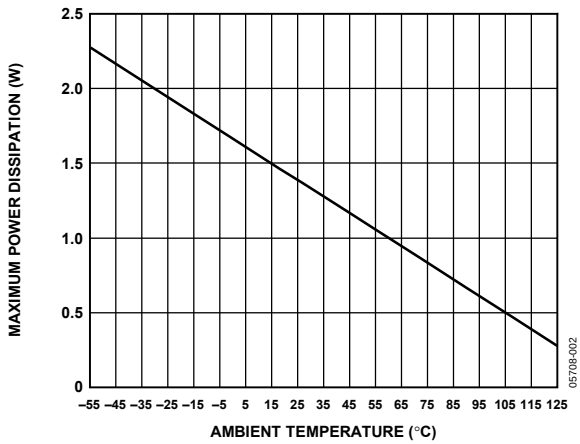


Figure 3. Maximum Power Dissipation vs. Temperature for a 4-Layer Board

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

R_L = 150 Ω and C_L = 4 pF, unless otherwise noted.

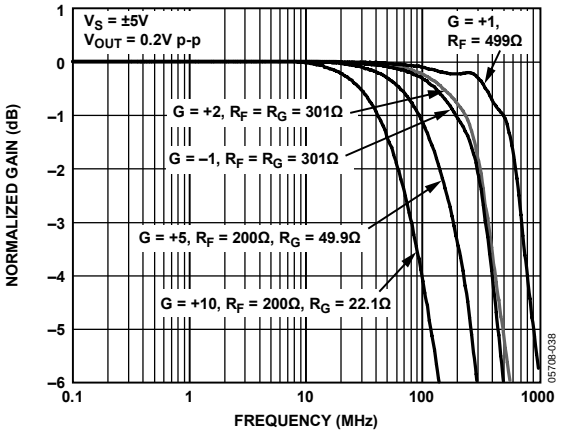


Figure 4. Small Signal Frequency Response for Various Gains

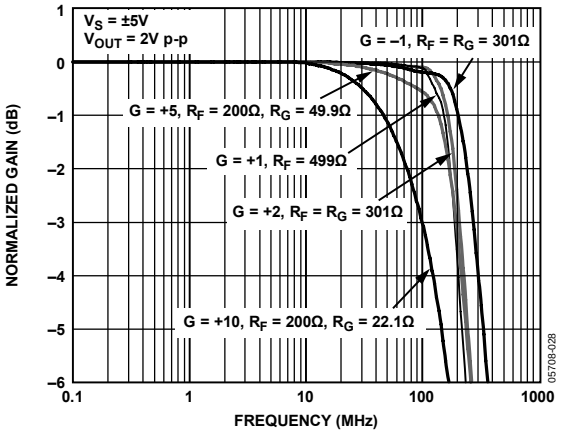


Figure 5. Large Signal Frequency Response for Various Gains

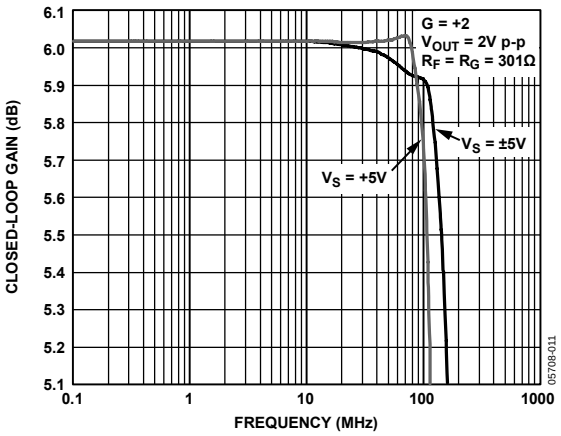


Figure 6. Large Signal 0.1 dB Flatness

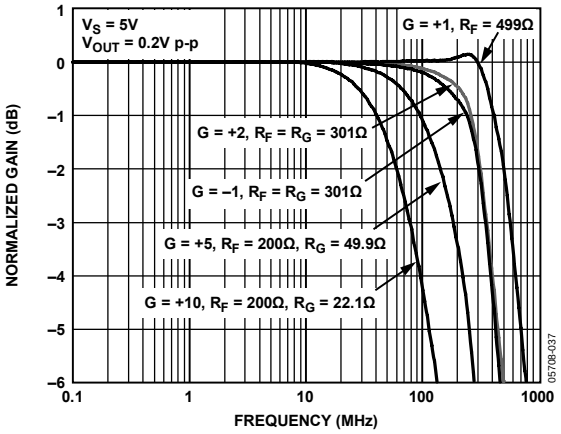


Figure 7. Small Signal Frequency Response for Various Gains

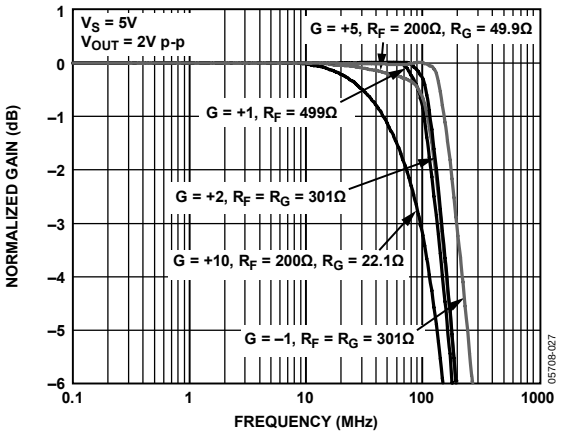


Figure 8. Large Signal Frequency Response for Various Gains

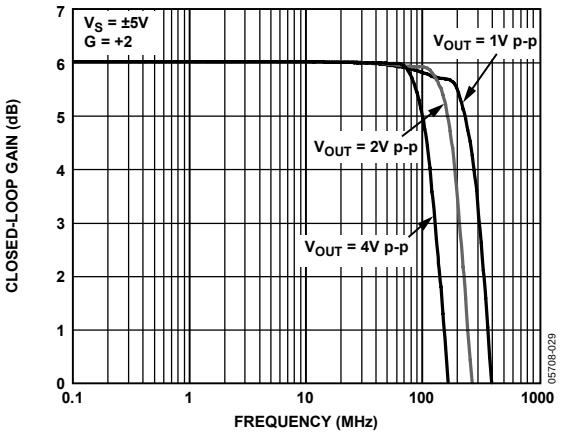


Figure 9. Large Signal Frequency Response for Various Output Levels

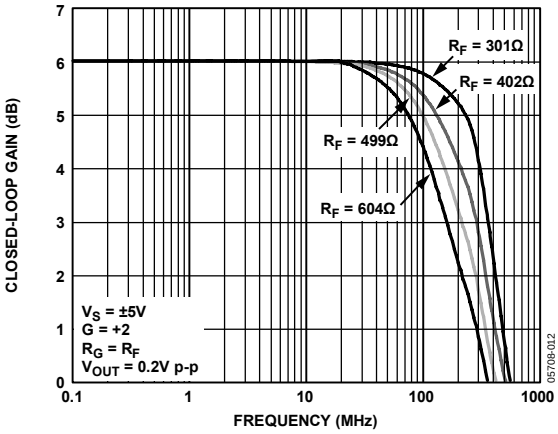


Figure 10. Small Signal Frequency Response vs. R_F

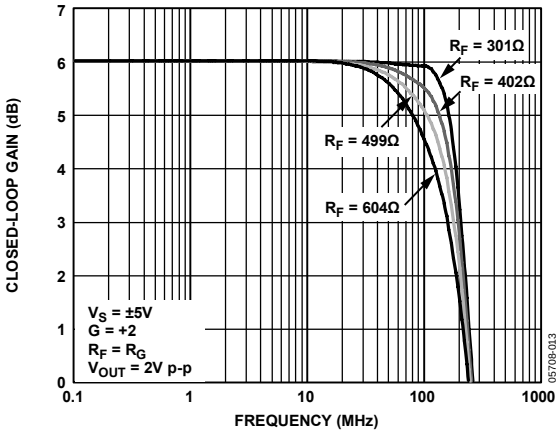


Figure 13. Large Signal Frequency Response vs. R_F

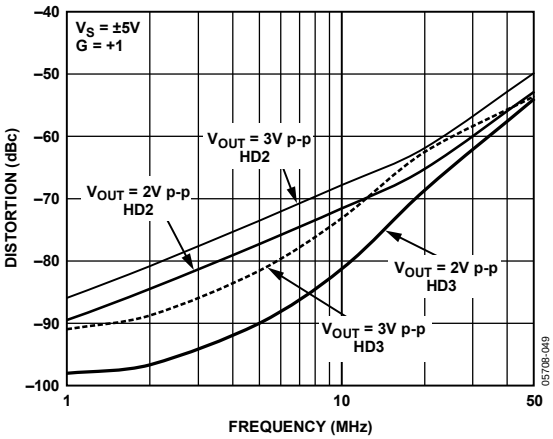


Figure 11. Harmonic Distortion vs. Frequency

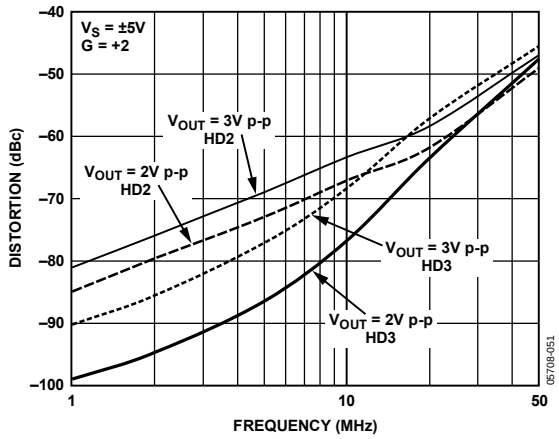


Figure 14. Harmonic Distortion vs. Frequency

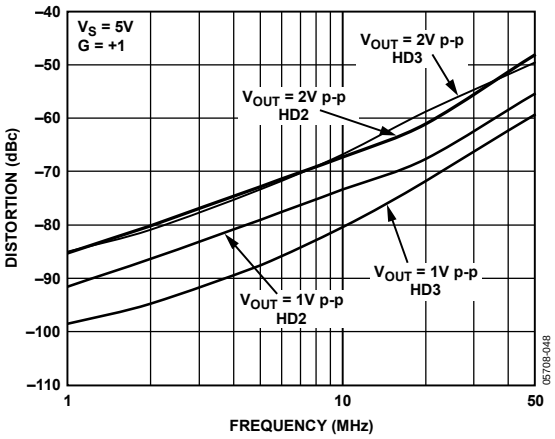


Figure 12. Harmonic Distortion vs. Frequency

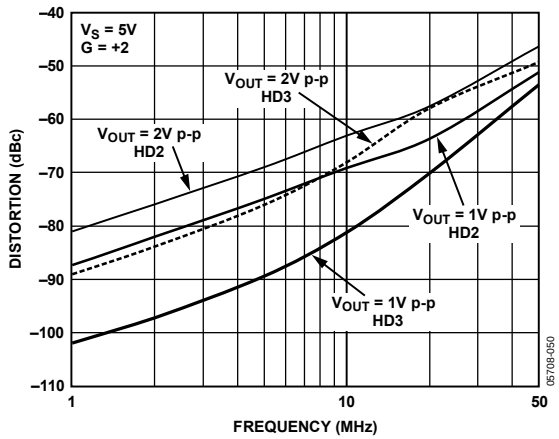


Figure 15. Harmonic Distortion vs. Frequency

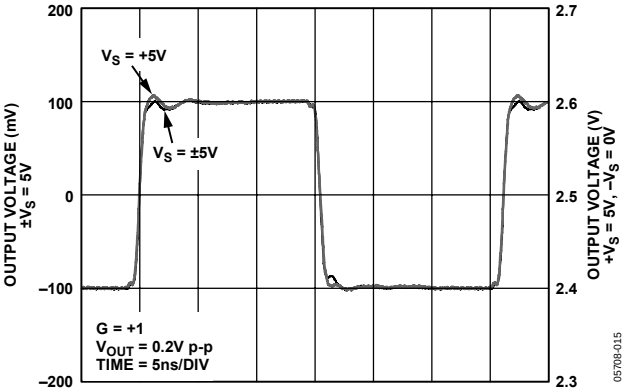


Figure 16. Small Signal Transient Response for Various Supplies

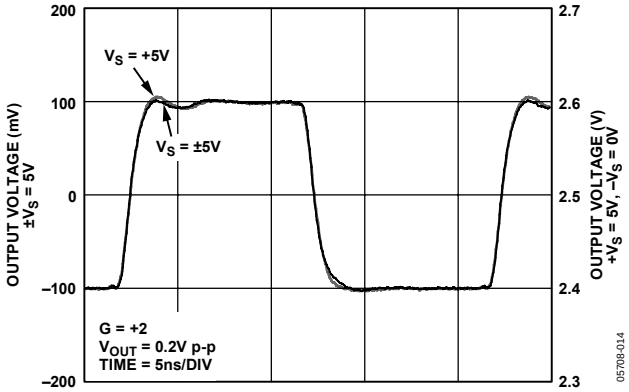


Figure 19. Small Signal Transient Response for Various Supplies

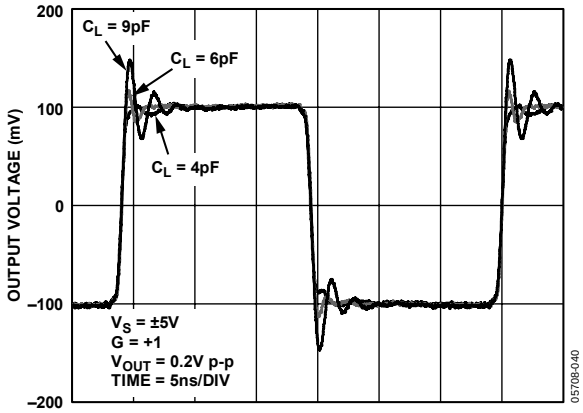


Figure 17. Small Signal Transient Response for Various Capacitor Loads

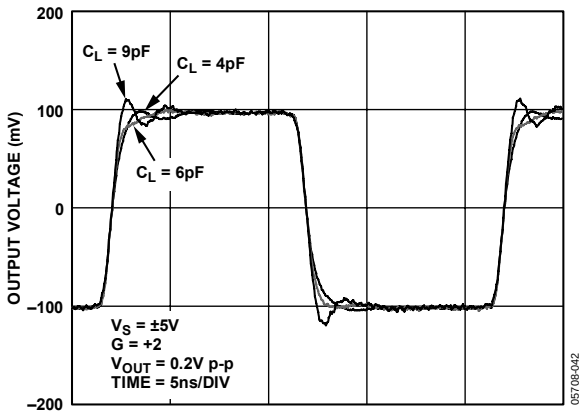


Figure 20. Small Signal Transient Response for Various Capacitor Loads

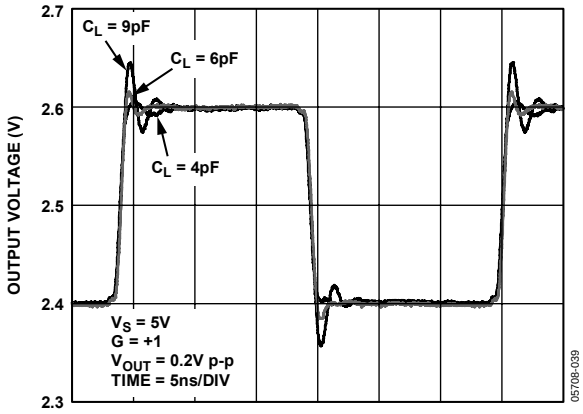


Figure 18. Small Signal Transient Response for Various Capacitor Loads

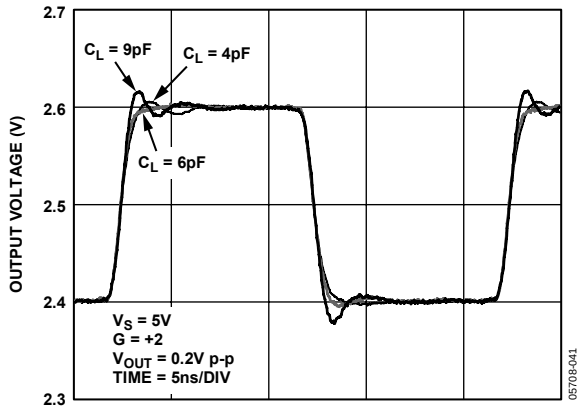


Figure 21. Small Signal Transient Response for Various Capacitor Loads

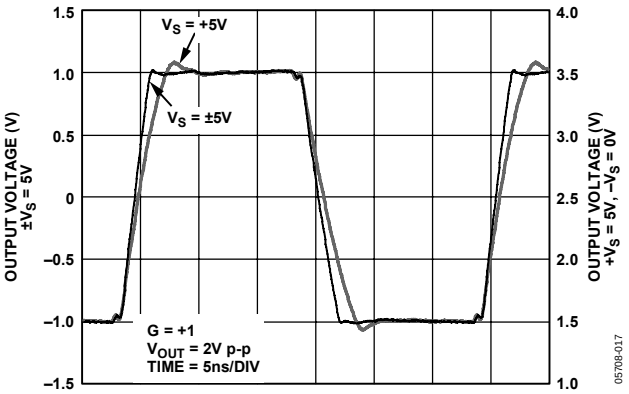


Figure 22. Large Signal Transient Response for Various Supplies

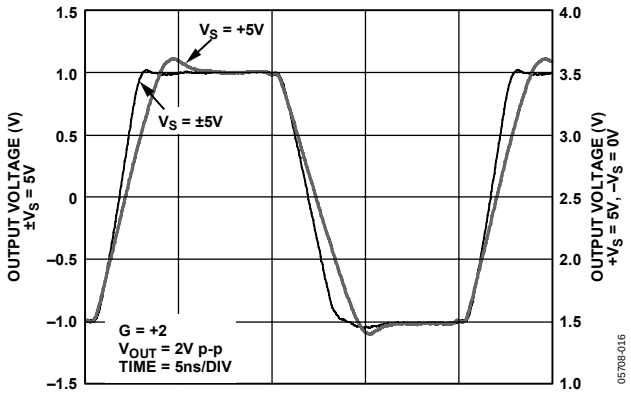


Figure 25. Large Signal Transient Response for Various Supplies

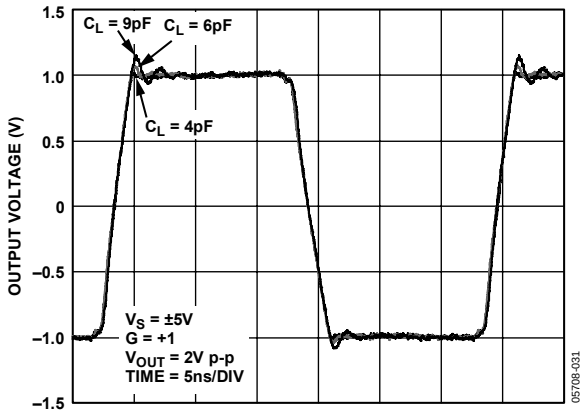


Figure 23. Large Signal Transient Response for Various Capacitor Loads

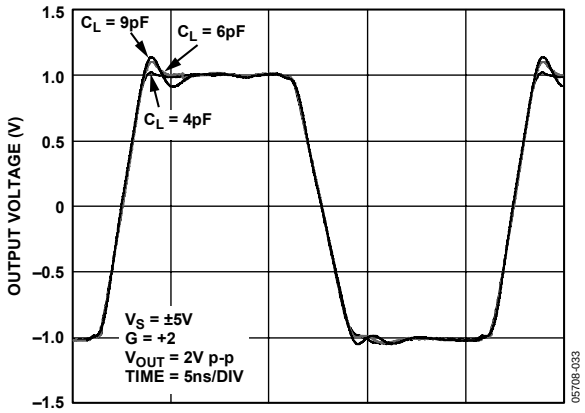


Figure 26. Large Signal Transient Response for Various Capacitor Loads

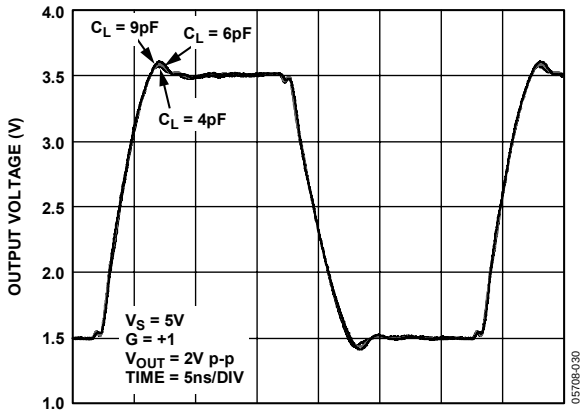


Figure 24. Large Signal Transient Response for Various Capacitor Loads

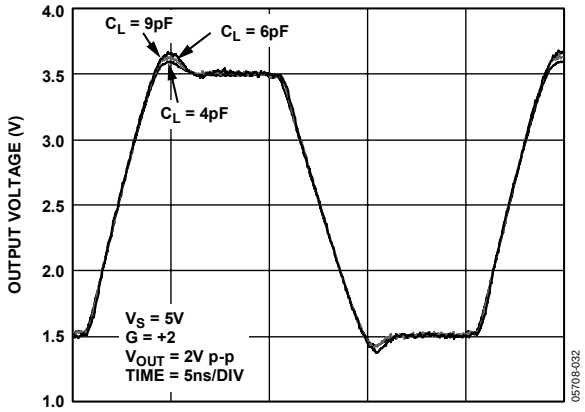


Figure 27. Large Signal Transient Response for Various Capacitor Loads

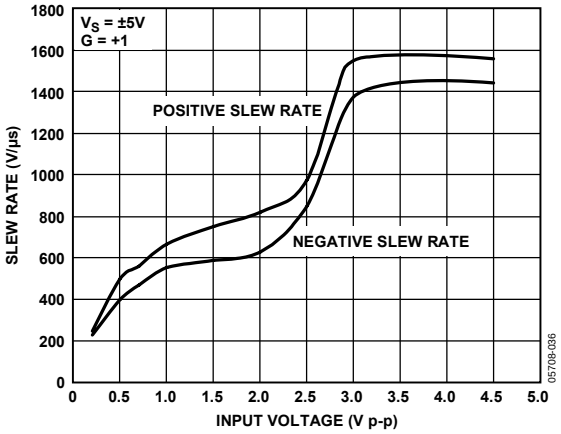


Figure 28. Slew Rate vs. Input Voltage

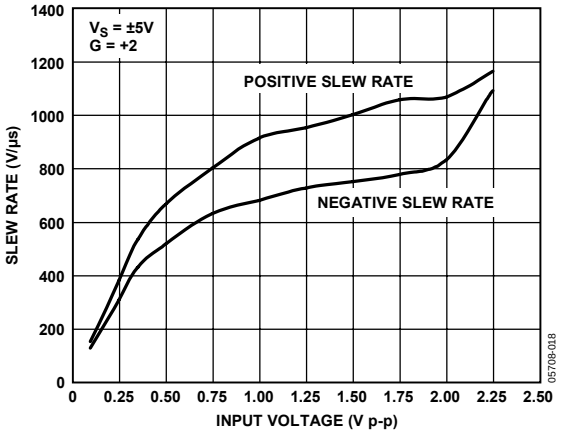


Figure 31. Slew Rate vs. Input Voltage

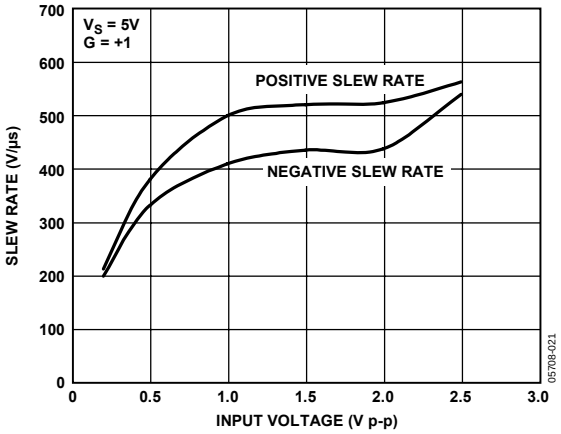


Figure 29. Slew Rate vs. Input Voltage

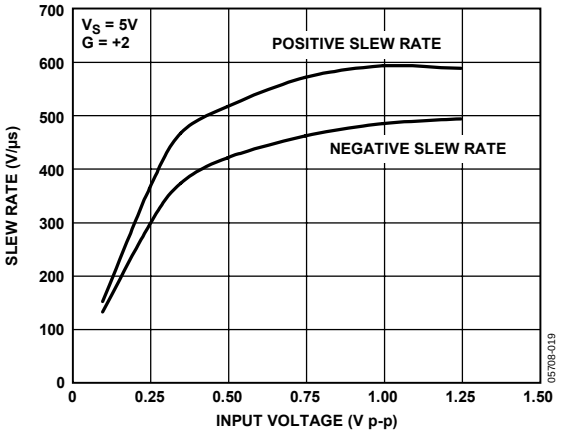


Figure 32. Slew Rate vs. Input Voltage

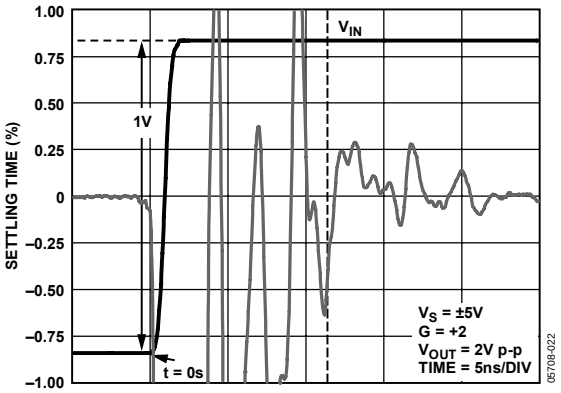


Figure 30. Settling Time Rising Edge

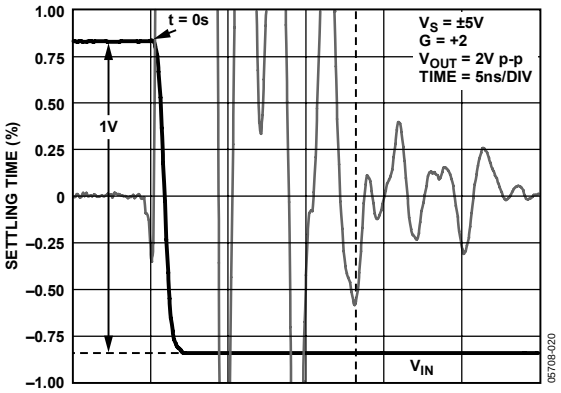


Figure 33. Settling Time Falling Edge

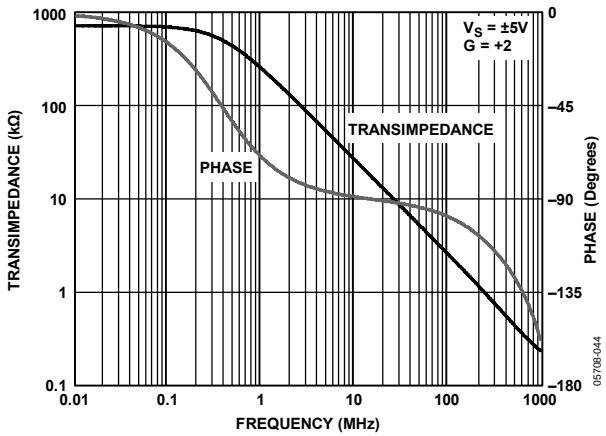


Figure 34. Transimpedance and Phase vs. Frequency

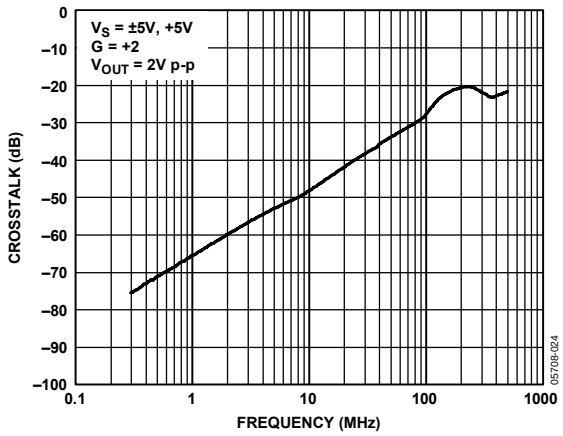


Figure 37. Large Signal All-Hostile Crosstalk

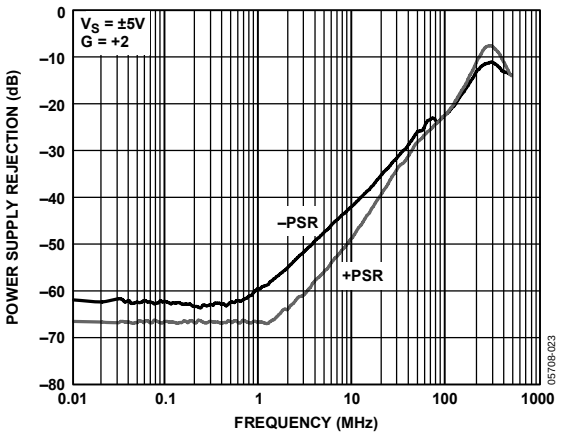


Figure 35. Power Supply Rejection vs. Frequency

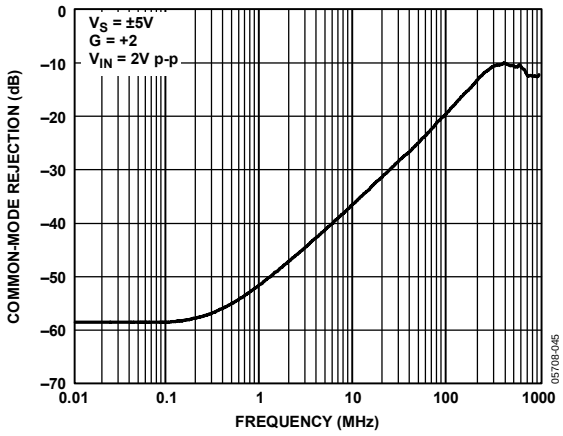


Figure 38. Common-Mode Rejection vs. Frequency

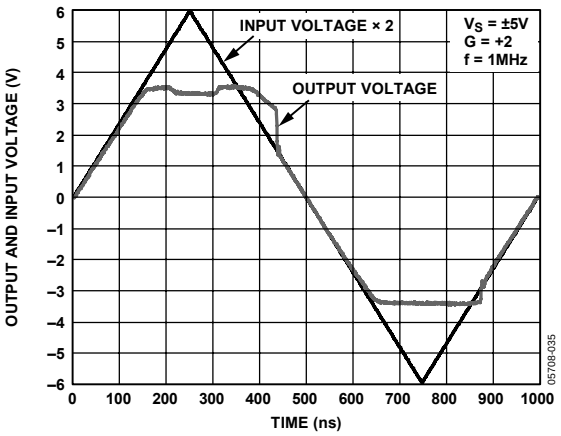


Figure 36. Output Overdrive Recovery

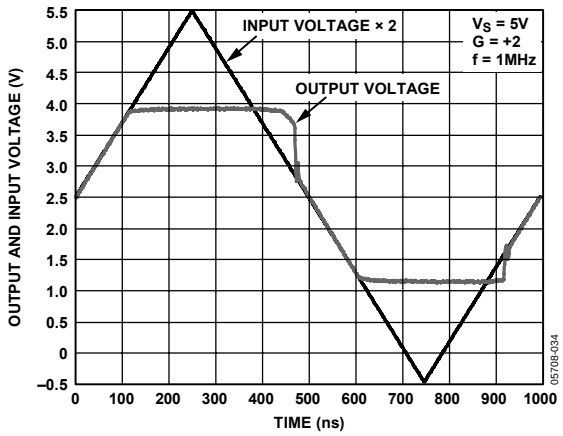


Figure 39. Output Overdrive Recovery

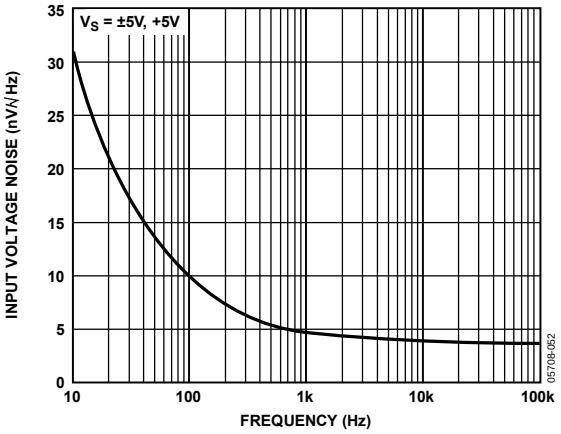


Figure 40. Input Voltage Noise vs. Frequency

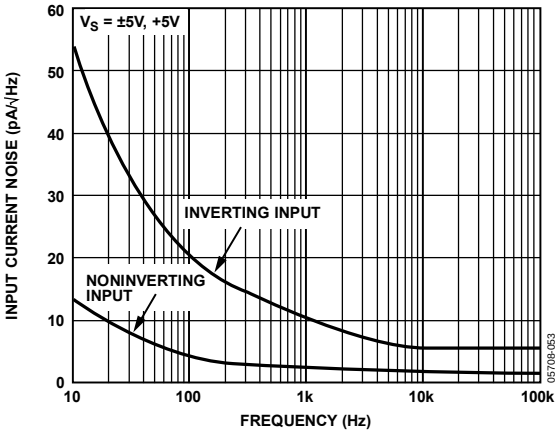


Figure 43. Input Current Noise vs. Frequency

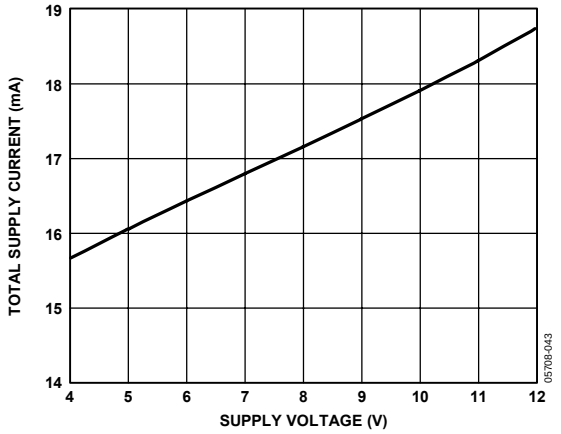


Figure 41. Total Supply Current vs. Supply Voltage

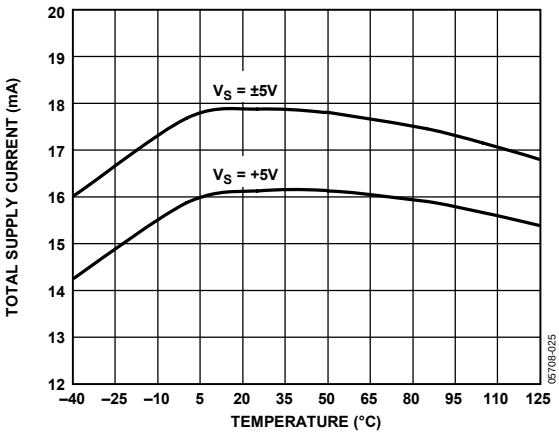


Figure 44. Total Supply Current at Various Supplies vs. Temperature

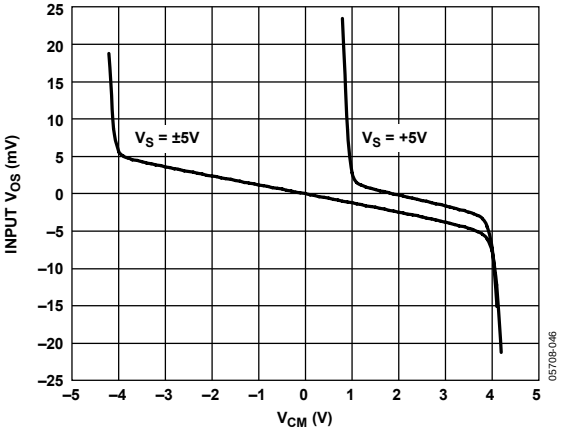


Figure 42. Input V_{OS} vs. Common-Mode Voltage

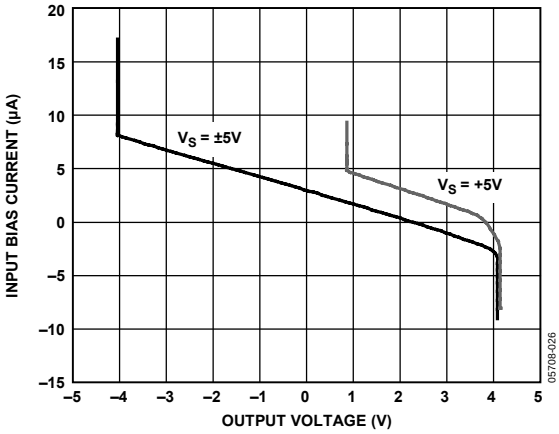


Figure 45. Input Bias Current vs. Output Voltage

APPLICATIONS

GAIN CONFIGURATIONS

Unlike conventional voltage feedback amplifiers, the feedback resistor has a direct impact on the closed-loop bandwidth and stability of the current feedback op amp circuit. Reducing the resistance below the recommended value can make the amplifier response peak and even become unstable. Increasing the size of the feedback resistor reduces the closed-loop bandwidth. Table 5 provides a convenient reference for quickly determining the feedback and gain set resistor values and bandwidth for common gain configurations.

Table 5. Recommended Values and Frequency Performance[1]

Gain	R_F (Ω)	R_G (Ω)	−3 dB SS BW (MHz)	Large Signal 0.1 dB Flatness
+1	499	N/A	730	90
−1	301	301	350	60
+2	301	301	370	100
+5	200	49.9	180	30
+10	200	22.1	80	15

[1] Conditions: V_S = ±5 V, T_A = 25°C, R_L = 150 Ω.

Figure 46 and Figure 47 show the typical noninverting and inverting configurations and recommended bypass capacitor values.

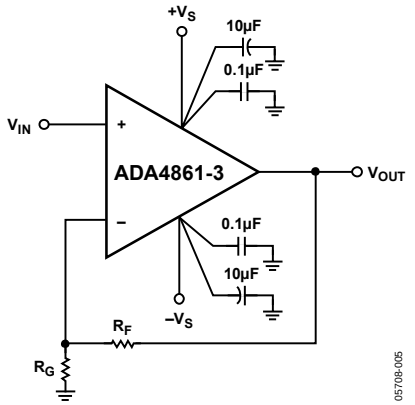


Figure 46. Noninverting Gain

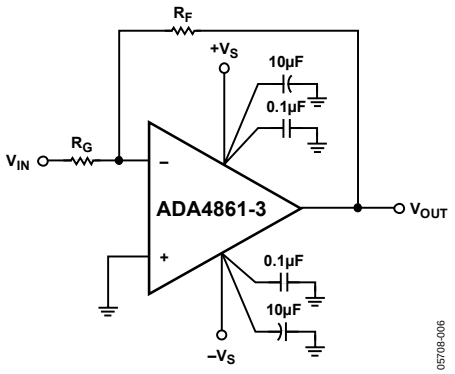


Figure 47. Inverting Gain

20 MHz ACTIVE LOW-PASS FILTER

The ADA4861-3 triple amplifier lends itself to higher order active filters. Figure 48 shows a 28 MHz, 6-pole, Sallen-Key low-pass filter.

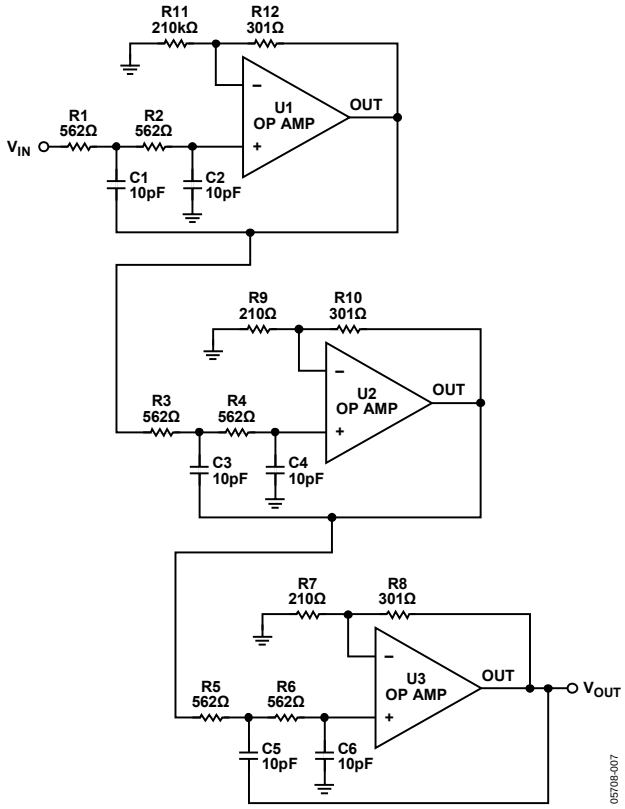


Figure 48. 28 MHz, 6-Pole Low-Pass Filter

The filter has a gain of approximately 23 dB and flat frequency response out to 22 MHz. This type of filter is commonly used at the output of a video DAC as a reconstruction filter. The frequency response of the filter is shown in Figure 49.

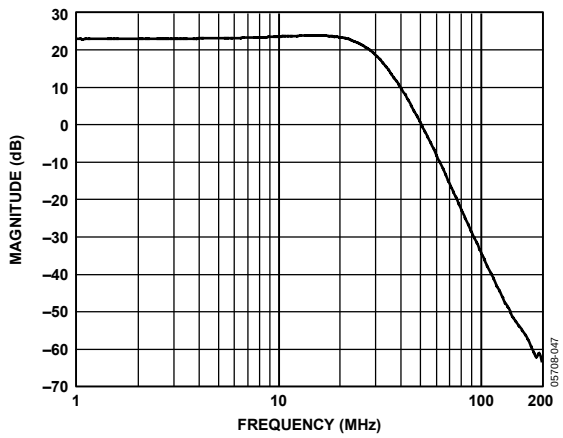


Figure 49. 20 MHz Low-Pass Filter Frequency Response

RGB VIDEO DRIVER

Figure 50 shows a typical RGB driver application using bipolar supplies. The gain of the amplifier is set at +2, where $R_F = R_G =$ 301 Ω. The amplifier inputs are terminated with shunt 75 Ω resistors, and the outputs have series 75 Ω resistors for proper video matching. In Figure 50, the POWER-DOWN pins are not shown connected to any signal source for simplicity. If the power-down function is not used, it is recommended that the power-down pins be tied to the negative supply and not be left floating (not connected).

For applications that require a fixed gain of +2, consider using the ADA4862-3 with integrated R_F and R_G. The ADA4862-3 is another high performance triple current feedback amplifier that can simplify design and reduce board area.

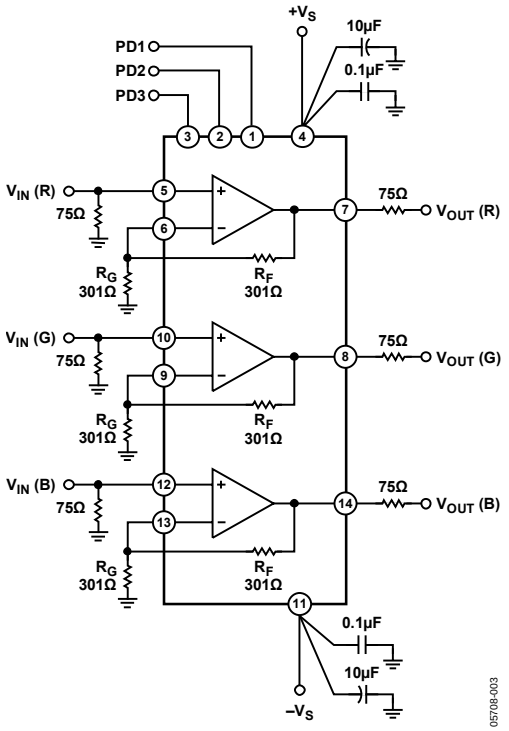


Figure 50. RGB Video Driver

DRIVING TWO VIDEO LOADS

In applications that require two video loads be driven simultaneously, the ADA4861-3 can deliver. Figure 51 shows the ADA4861-3 configured with dual video loads. Figure 52 shows the dual video load 0.1 dB bandwidth performance.

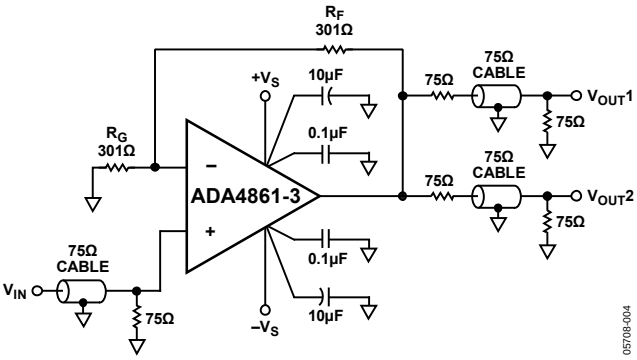


Figure 51. Video Driver Schematic for Two Video Loads

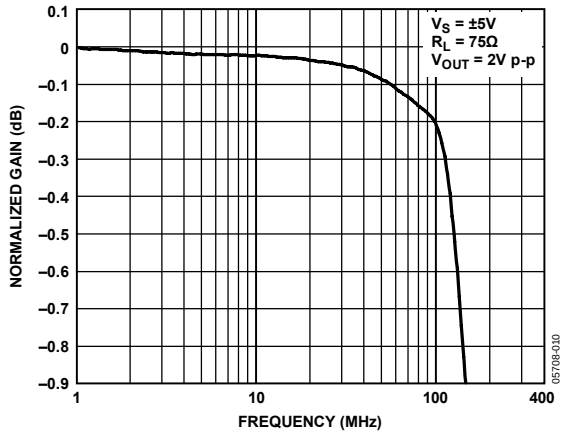


Figure 52. Large Signal Frequency Response for Various Supplies, R_L = 75 Ω

POWER-DOWN PINS

The ADA4861-3 is equipped with three independent POWER DOWN pins, one for each amplifier. This allows the user the ability to reduce the quiescent supply current when an amplifier is inactive. The power-down threshold levels are derived from the voltage applied to the $-V_S$ pin. When used in single-supply applications, this is especially useful with conventional logic levels. The amplifier is powered down when the voltage applied to the POWER DOWN pins is greater than $-V_S$ + 1 V. In a single-supply application, this is > +1 V (that is, 0 V + 1 V), in a ±5 V supply application, the voltage is > −4 V. The amplifier is enabled whenever the POWER DOWN pins are left either open or the voltage on the POWER DOWN pins is lower than 1 V above $-V_S$. If the POWER DOWN pins are not used, it is best to connect them to the negative supply.

SINGLE-SUPPLY OPERATION

The ADA4861-3 can also be operated from a single power supply. Figure 53 shows the schematic for a single 5 V supply video driver. The input signal is ac-coupled into the amplifier via C1. Resistor R2 and Resistor R4 establish the input midsupply reference for the amplifier. Capacitor C5 prevents constant current from being drawn through the gain set resistor and enables the ADA4861-3 at dc to provide unity gain to the input midsupply voltage, thereby establishing the output voltage dc operating point. Capacitor C6 is the output coupling capacitor. For more information on single-supply operation of op amps, see www.analog.com/library/analogDialogue/archives/35-02/avoiding/.

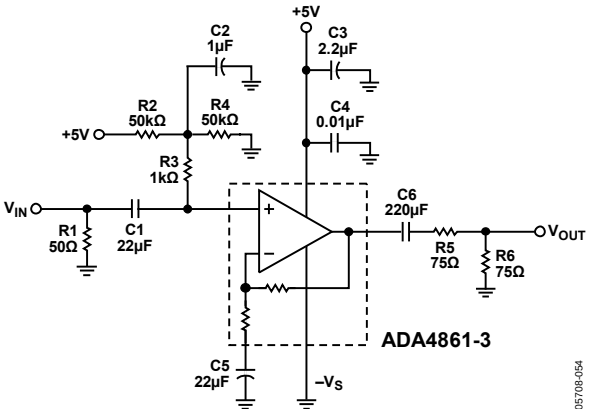


Figure 53. Single-Supply Video Driver Schematic

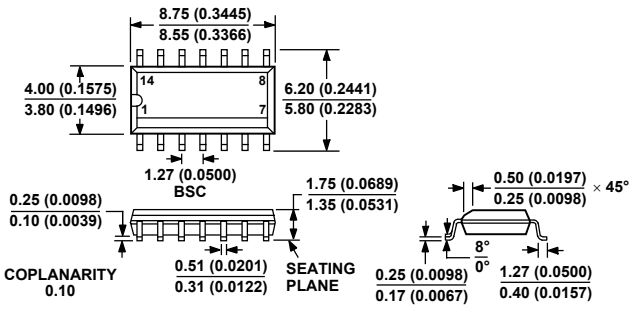
POWER SUPPLY BYPASSING

Careful attention must be paid to bypassing the power supply pins of the ADA4861-3. High quality capacitors with low equivalent series resistance (ESR), such as multilayer ceramic capacitors (MLCCs), should be used to minimize supply voltage ripple and power dissipation. A large, usually tantalum, 2.2 µF to 47 µF capacitor located in proximity to the ADA4861-3 is required to provide good decoupling for lower frequency signals. The actual value is determined by the circuit transient and frequency requirements. In addition, 0.1 µF MLCC decoupling capacitors should be located as close to each of the power supply pins as is physically possible, no more than 1/8 inch away. The ground returns should terminate immediately into the ground plane. Locating the bypass capacitor return close to the load return minimizes ground loops and improves performance.

LAYOUT

As is the case with all high-speed applications, careful attention to printed circuit board (PCB) layout details prevents associated board parasitics from becoming problematic. The ADA4861-3 can operate at up to 730 MHz; therefore, proper RF design techniques must be employed. The PCB should have a ground plane covering all unused portions of the component side of the board to provide a low impedance return path. Removing the ground plane on all layers from the area near and under the input and output pins reduces stray capacitance. Signal lines connecting the feedback and gain resistors should be kept as short as possible to minimize the inductance and stray capacitance associated with these traces. Termination resistors and loads should be located as close as possible to their respective inputs and outputs. Input and output traces should be kept as far apart as possible to minimize coupling (crosstalk) through the board. Adherence to microstrip or stripline design techniques for long signal traces (greater than 1 inch) is recommended. For more information on high speed board layout, go to: www.analog.com and www.analog.com/library/analogDialogue/archives/39-09/layout.html.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 54. 14-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-14)
Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Ordering Quantity
ADA4861-3YRZ[1]	–40°C to +105°C	14-Lead SOIC_N	R-14	1
ADA4861-3YRZ-RL[1]	–40°C to +105°C	14-Lead SOIC_N	R-14	2,500
ADA4861-3YRZ-RL7[1]	–40°C to +105°C	14-Lead SOIC_N	R-14	1,000

[1] Z = Pb-free part.

©2006 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners.
D05708-0-3/06(A)